L Number				
1 namber		inventive adj edge adj structure	USPAT;	2003/01/28 09:18
1	i	inventive adj edge daj seracture	US-PGPUB;	2003/01/28 03.18
	1		EPO; JPO;	
}	1		DERWENT;	1
			IBM TDB	
8	28	high adj voltage with edge adj structure	USPAT;	2003/01/28 09:18
			US-PGPUB;	2000,01,20 0,10
	1		EPO; JPO;	
	}		DERWENT;	
			IBM TDB	1
15	529	(257/170,490,495).CCLS.	USPĀT;	2003/01/28 10:49
			US-PGPUB;	
	1		EPO; JPO;	1
	}		DERWENT;	
			IBM_TDB	
22	2991	edge with high near (volt voltage)	USPAT;	2003/01/28 10:51
			US-PGPUB;	
			EPO; JPO;	·
1			DERWENT;	
20	10	//053/130 400 405) 0075) } / '	IBM_TDB	0000 /01 /00 10 50
29	19	((257/170,490,495).CCLS.) and (edge with	USPAT;	2003/01/28 10:51
		high near (volt voltage))	US-PGPUB;	
ĺ			EPO; JPO; DERWENT;	•
1			IBM TDB	:
36	15	5324971.URPN.	USPAT	2003/01/28 10:55
37	6	3324971.0RPN. ("4492974" "4567502" "4707719"	USPAT	2003/01/28 10:55
		"4831424" "5128730" "5162966").PN.	OSERI	2003/01/20 10:33
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